



MJE3055TG Information



For Reference Only

Part Number MJE3055TG

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 60V 10A TO220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MJE3055TG Specifications

Manufacturer Part Number	MJE3055TG
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-220-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	10A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	8V @ 3.3A, 10A
Current - Collector Cutoff (Max)	700μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 4A, 4V
Power - Max	75W
Frequency - Transition	2MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3
Supplier Device Package	TO-220AB
	Report errors?

MJE3055TG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MJE3055TG Payment Methods



















MJE3055TG Shipping Methods













If you have any question about MJE3055TG, please do not hesitate to contact us!

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